GLAST DETECTOR TESTS

QA of 4" HAMAMATSU PROTOTYPE TOWER SI SENSORS

	Careful:	use gloves use vacuum tip to handle detectors avoid contacts with metal		
St	andard I	Measurements to be performed:	Set of sensors	
1.	Measurements of dimensions			
	1.1	check number	all	
	1.2	visual inspection both sides (scratches etc)	all	
	1.3	mechanical dimensions		
	1.3.1	overall outside dimensions @ 4 corners	all	
	1.3.2	distance of bias line - edge at 3 places per edge	all	
	1.1.3	strip pitch, implant width, internal dimensio	ns 1/batch	
2.	Measure	ments of bulk electrical properties		
	2.1	i-V curve to 300V (3 contacts)	all	
	2.2	C-V curve at 10kHz	all	
3.	Measurements on all strips			
	3.1	current at 150V and 200V	all	
	3.2	chack for bad coupling capacitor up to 30V	all	
4.	Measurements on few selected strips			
	4.1	interstrip capacitance as a function of bias	1/batch	
	4.2	interstrip isolation	1/batch	
	4.3	coupling caps	1/batch	
	4.4	bias resistors (both sides, center)	1/batch	
	4.5	resistance of Al metal	1/batch	
	4.6	resistance of Al bypass strip	1/batch	
5.	Measurements with read-out			
	5.1	check that bypassing works on shorted capacitor	once	
	5.2	noise	few	
6.	Radiation Measurements with 60 Co in steps of 5, 10, 20kRad			
	6.2	Repeat Measurements 2.1, 2.2, 3.1, 5.2 after every step	p few	
	6.2	Repeat 2.1, 2.2, 3.1, 3.2, 4.1, 4.2, 4.3, 4.4, 5.2 after 20kRa	nd few	